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Contact: Bob Decker, Wall Street Communications Phone: 650-323-3936 Fax: 650-323-5650

Email: Bob.Decker@wallstcom.com

4 milliohms in the SO-8: Vishay Siliconix Sets New Record For Power MOSFET On-Resistance

New Package Technology Yields Nearly Twofold Improvement Over Previous State-of-the-Art

SANTA CLARA, CALIFORNIA - December 9, 1998 - Vishay Siliconix today announced a major breakthrough in power MOSFET performance with the release of an n-channel device offering maximum on-resistance of just 4 milliohms in the SO-8 package. The new Si4430DY is one of three new LITTLE FOOT® devices that combine Vishay Siliconix's 32-million cell TrenchFET® silicon with an advanced technique that dramatically reduces the packaging contribution to overall device resistance.



"With our 32 million cells per square inch TrenchFET technology, which remains the

state of the art for power MOSFETs, Vishay Siliconix power MOSFETs reached the point where approximately half the total on-resistance for an SO-8 device was in the package components rather than the silicon," said Dr. Felix Zandman, Chairman of the Board and CEO of Vishay Intertechnology, Inc. "The next logical step was to reduce the resistance of the package itself, which is what we have done in these new LITTLE FOOT devices, with dramatic results."

To create these new LITTLE FOOT devices, Vishay Siliconix has developed a proprietary PowerConnectTM technology to replace the bond wires found in traditional power MOSFET packages with a direct connection between the silicon die and the copper lead frame. The result is to increase the number of leads that are directly connected to the chip.

This maximizes the thermal performance and increases the package area available for active silicon. Certain aspects of this technology are the subjects of a pending patent application.

The new 4-milliohm Si4430DY can handle up to 22 A of current and will dissipate up to 3.5 W, a nearly two-fold improvement over any previous power MOSFET in the SO-8 package. With power dissipation capabilities comparable to much larger devices, it will allow designers of Pentium II power conversion circuitry in desktop computers to replace the DPAK power MOSFETs now used in this application with the much smaller LITTLE FOOT SO-8 device. Current handling is so improved compared to previous-generation devices that the number of MOSFETs used as switching elements

can be cut in half.

Using the same packaging technology in a much smaller footprint, Vishay Siliconix is also offering two p-channel devices for bidirectional blocking battery disconnect applications. The new Si3801DV and Si3803DV are the first products on the market to provide a complete reverse blocking function with two MOSFETs in a LITTLE FOOT TSOP-6, allowing designers to implement dual battery systems with a package measuring just 3.02 x 2.84 x 1.01 mm. These new devices will allow manufacturers to provide this useful feature more affordably, and with less board space, than was ever before possible.

The new Si3801DV and Si3803DV provide the industry's lowest on-resistance for a p-channel battery switch in this package type, just 250 milliohm total for both MOSFETs in series. For very low-voltage systems, the Si3803DV is specified for operation at gate drives as low as 1.8 V. Vishay Siliconix is the industry's first supplier to offer power MOSFETs with a 1.8-V operating voltage. An additional 12 such devices, which are essential components in the development of ultra-low-voltage portable systems, are being separately released by Vishay Siliconix.

Samples of the Si4430DY, Si3801DV, and Si3803DV are available now. Production quantities are available in Q4 1998 for the Si3801DV and Si3803DV, and in Q1 1999 for the Si4430DY.

Siliconix (NASDAQ: "SILI"), a company of Vishay Intertechnology, Inc., is a leading manufacturer of power MOSFETs, power ICs, and analog signal processing devices for computers, cell phones, fixed communications networks, automobiles, and other electronic systems. With 1997 worldwide sales of \$322 million, the Company's facilities include Class 1, six-inch wafer fabs dedicated to the manufacture of power products in Santa Clara, California and Itzehoe, Germany. Analog switches, analog multiplexers, and low-power transistors are fabricated in the Company's four-inch wafer fab in Santa Clara and by a subcontractor in Beijing, China. Assembly and test facilities include a Company-owned facility in Taiwan, a joint venture in Shanghai, China, and subcontractors in the Philippines, India, and Taiwan.

Vishay Intertechnology, Inc. (NYSE: VSH), a Fortune 1,000 company with revenues running at an annual rate of approximately \$1.6 billion, is the largest U.S. and European manufacturer of passive electronic components (resistors, capacitors, inductors) and a major producer of discrete semiconductors (diodes, optoelectronics, transistors), IrDCs and power ICs. The company's components are vital to the operation of everything electronic and can be found in products produced by virtually all U.S. and European electronics equipment manufacturers. With headquarters in Malvern, Pennsylvania, Vishay employs over 20,000 people in over 60 facilities in the U.S., Mexico, Germany, Austria, Hungary, the United Kingdom, France, Portugal, the Czech Republic, Israel, Japan, Taiwan, China and the Philippines.

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